



# CPH6635

## Power MOSFET

30V, 0.4A, 3.7Ω, -20V, -1.5A, 280mΩ, Complementary Dual CPH6

ON Semiconductor®

<http://onsemi.com>

### Features

- Excellent ON-resistance characteristic (P-Channel :  $R_{DS(on)1}=215m\Omega$  (typ.))
- Optimal for load switch use (N-Channel for drive is embedded)
- N-Channel : 1.5V drive, P-Channel : 1.8V drive
- Halogen Free compliance

### Specifications

#### Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	N-channel	P-channel	Unit
Drain to Source Voltage	$V_{DSS}$		30	-20	V
Gate to Source Voltage	$V_{GSS}$		$\pm 10$	$\pm 10$	V
Drain Current (DC)	$I_D$		0.4	-1.5	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu s$ , duty cycles $\leq 1\%$	1.6	-6.0	A
Allowable Power Dissipation	$P_D$	When mounted on ceramic substrate (900mm <sup>2</sup> x 0.8mm) 1unit	0.8		W
Channel Temperature	$T_{ch}$		150		$^\circ C$
Storage Temperature	$T_{stg}$		-55 to +150		$^\circ C$

This product is designed to "ESD immunity < 200V\*\*", so please take care when handling.

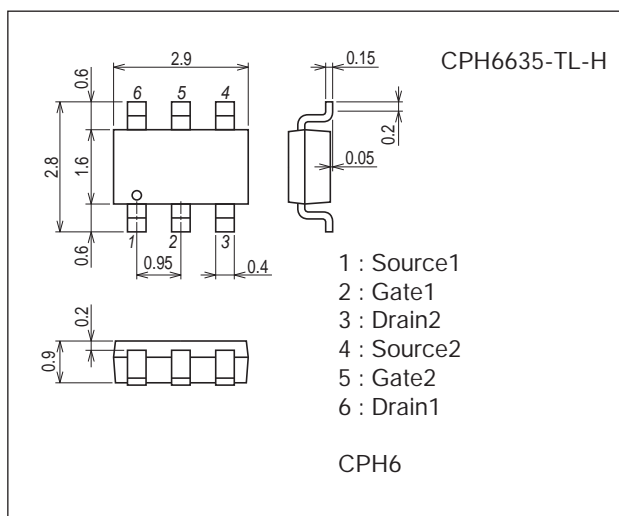
\* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### Package Dimensions

unit : mm (typ)

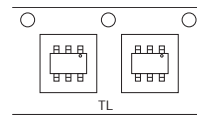
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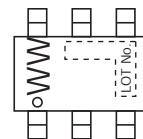
### Ordering & Package Information

Device	Package	Shipping	memo
CPH6635-TL-H	CPH6 SC-74, SOT-26, SOT-45	3,000 pcs./reel	Pb Free and Halogen Free

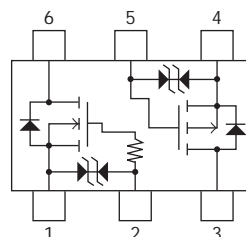
### Packing Type: TL



### Marking



### Electrical Connection



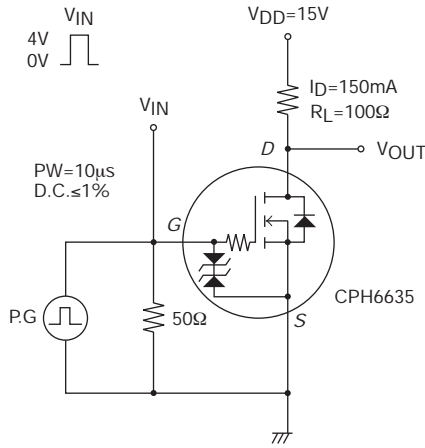
# CPH6635

## Electrical Characteristics at Ta=25°C

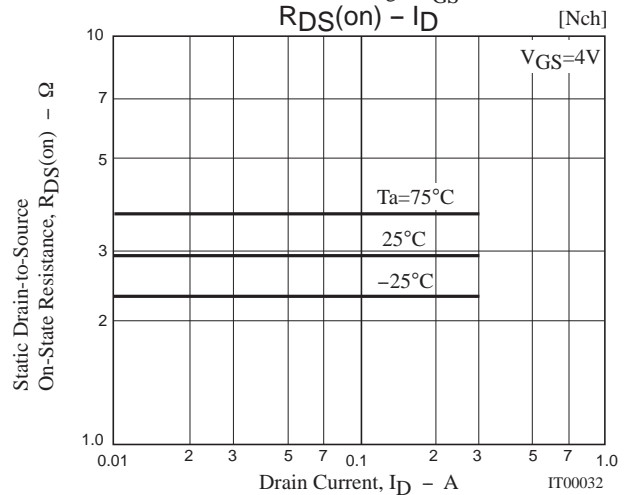
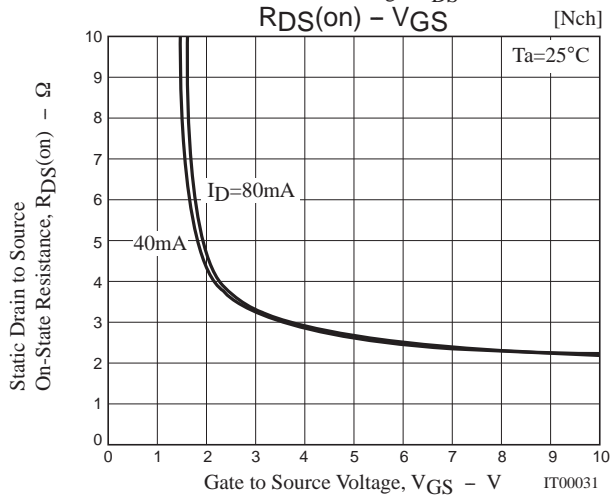
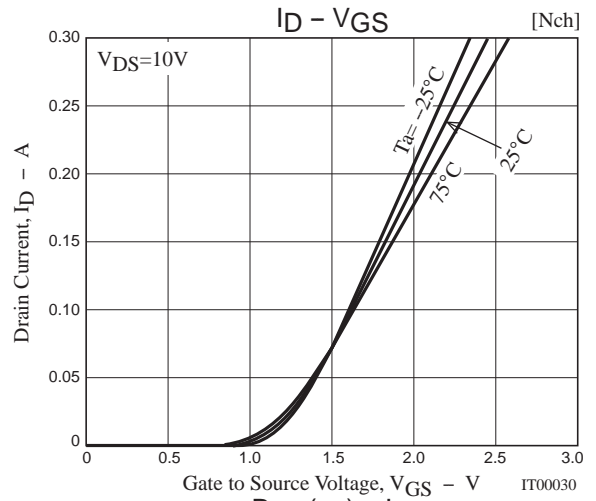
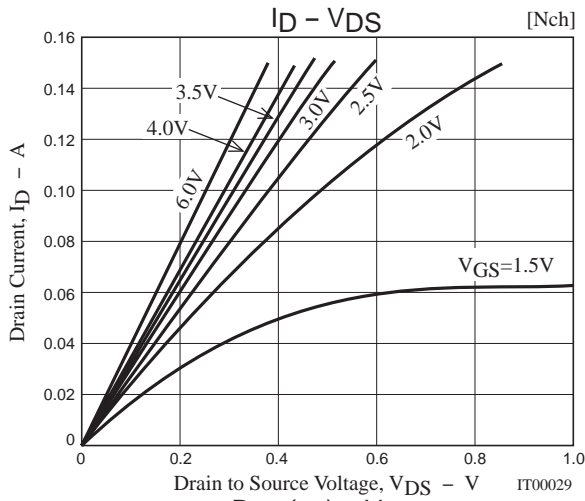
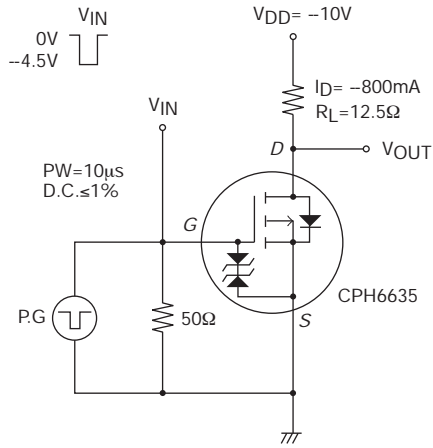
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[N-channel]						
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=100μA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=80mA		0.22		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=80mA, VGS=4V		2.9	3.7	Ω
	RDS(on)2	ID=40mA, VGS=2.5V		3.7	5.2	Ω
	RDS(on)3	ID=10mA, VGS=1.5V		6.4	12.8	Ω
Input Capacitance	Ciss	VDS=10V, f=1MHz		7		pF
Output Capacitance	Coss			5.9		pF
Reverse Transfer Capacitance	Crss			2.3		pF
Turn-ON Delay Time	t <sub>d(on)</sub>		See specified Test Circuit.		19	
Rise Time	t <sub>r</sub>			65		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>			155		ns
Fall Time	t <sub>f</sub>			120		ns
Total Gate Charge	Qg	VDS=10V, VGS=10V, ID=150mA			1.58	
Gate to Source Charge	Qgs			0.26		nC
Gate to Drain "Miller" Charge	Qgd			0.31		nC
Diode Forward Voltage	VSD	IS=150mA, VGS=0V		0.87	1.2	V
[P-channel]						
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-20V, VGS=0V			-1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-0.4		-1.4	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-800mA		1.9		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=-800mA, VGS=-4.5V		215	280	mΩ
	RDS(on)2	ID=-400mA, VGS=-2.5V		310	434	mΩ
	RDS(on)3	ID=-200mA, VGS=-1.8V		450	675	mΩ
Input Capacitance	Ciss	VDS=-10V, f=1MHz		120		pF
Output Capacitance	Coss			26		pF
Reverse Transfer Capacitance	Crss			20		pF
Turn-ON Delay Time	t <sub>d(on)</sub>		See specified Test Circuit.		5.3	
Rise Time	t <sub>r</sub>			9.7		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>			16		ns
Fall Time	t <sub>f</sub>			14		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-4V, ID=-1.5A			1.7	
Gate to Source Charge	Qgs			0.28		nC
Gate to Drain "Miller" Charge	Qgd			0.47		nC
Diode Forward Voltage	VSD	IS=-1.5A, VGS=0V		-0.9	-1.5	V

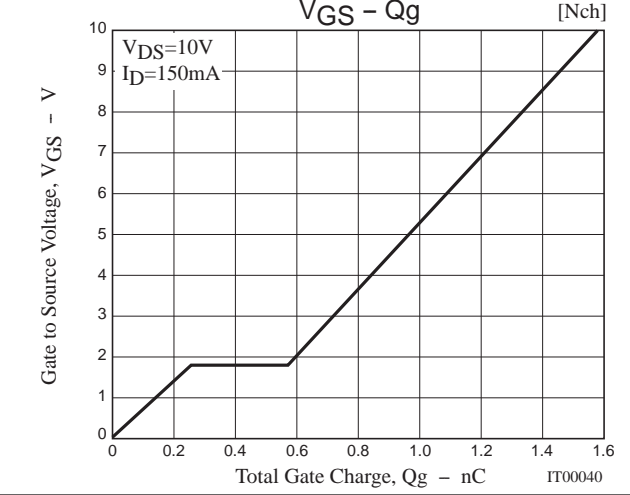
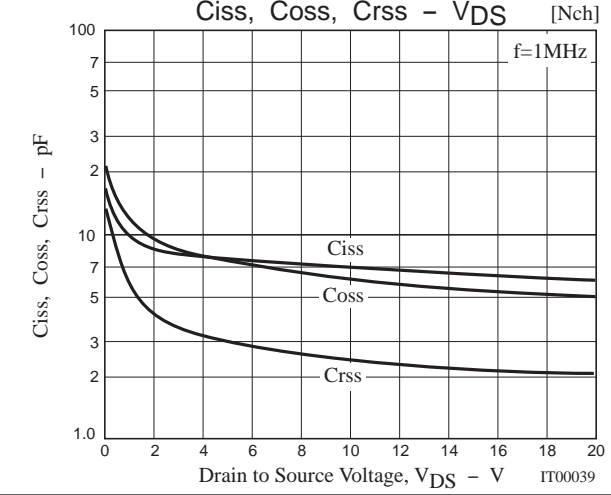
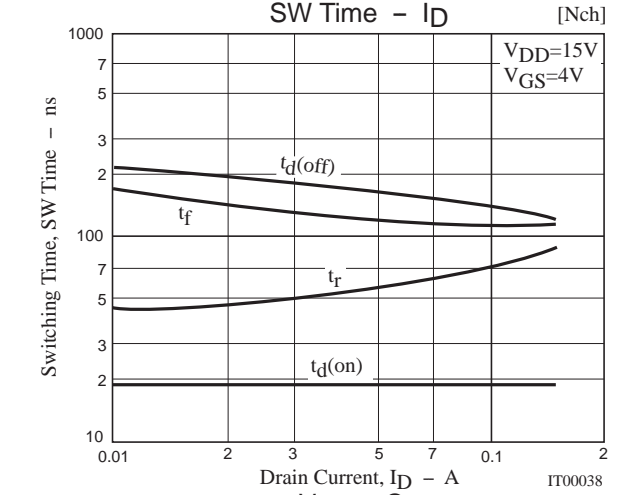
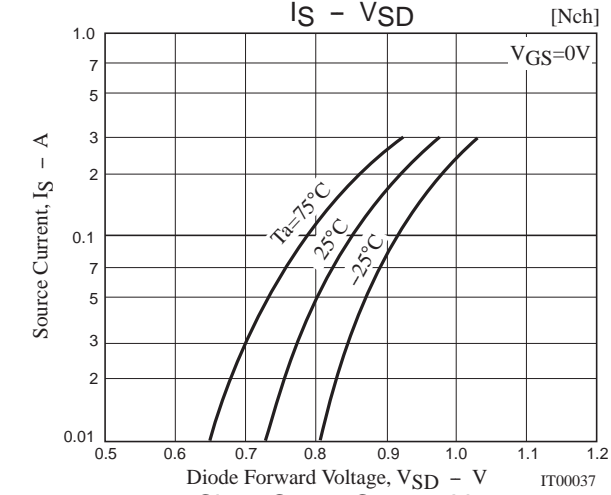
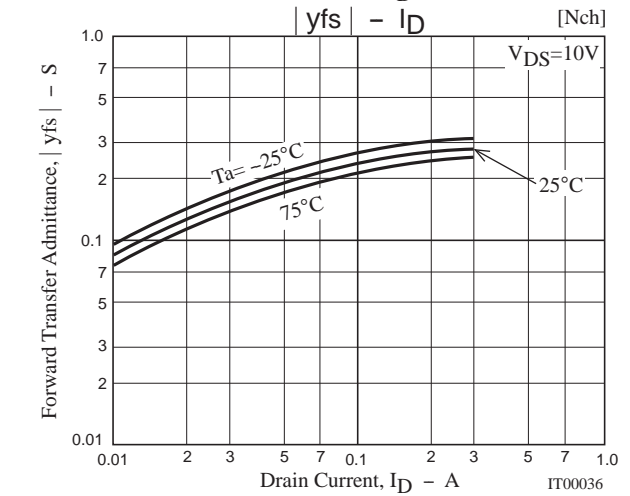
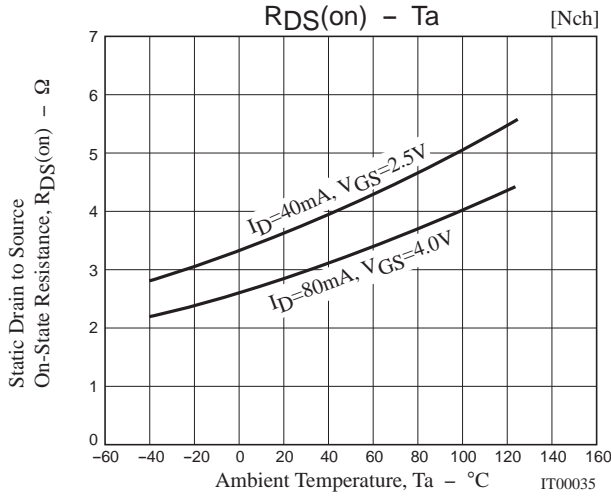
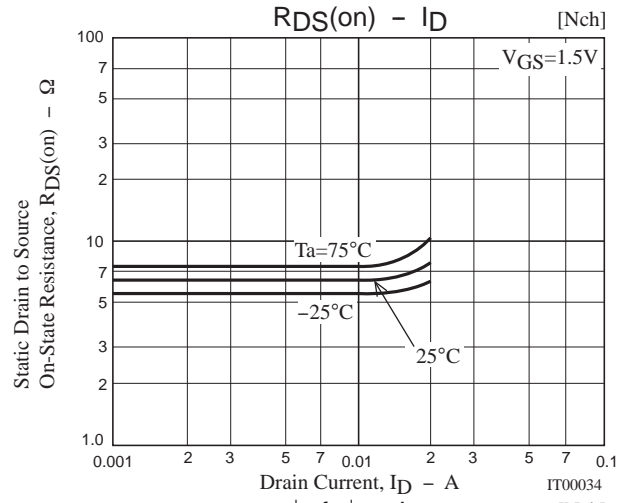
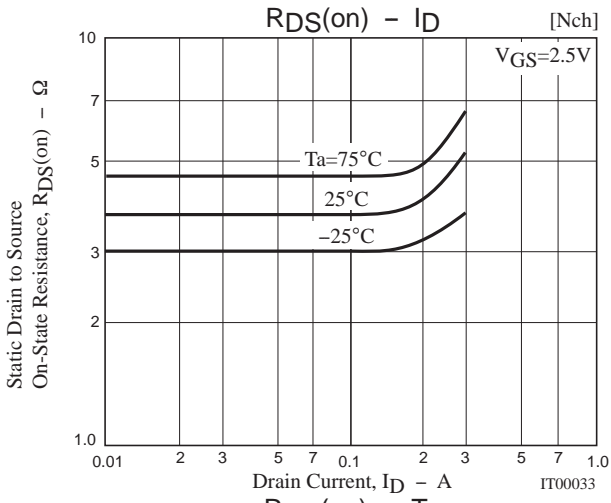
Switching Time Test Circuit

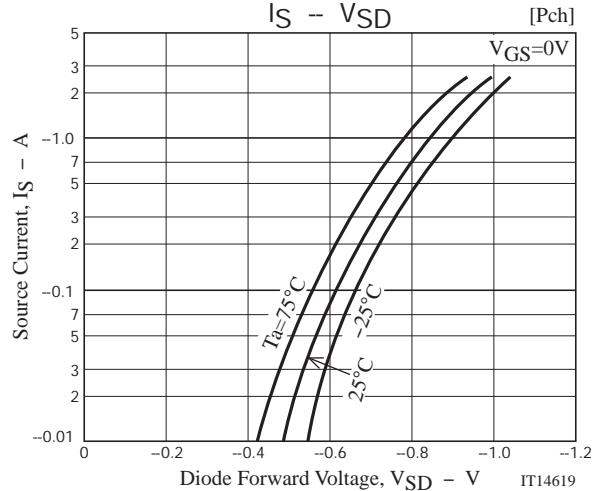
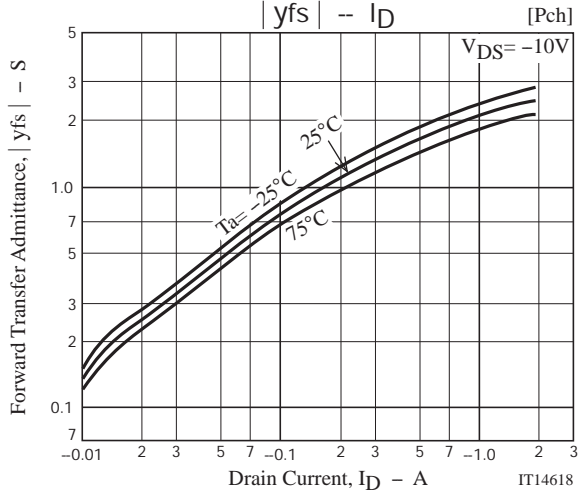
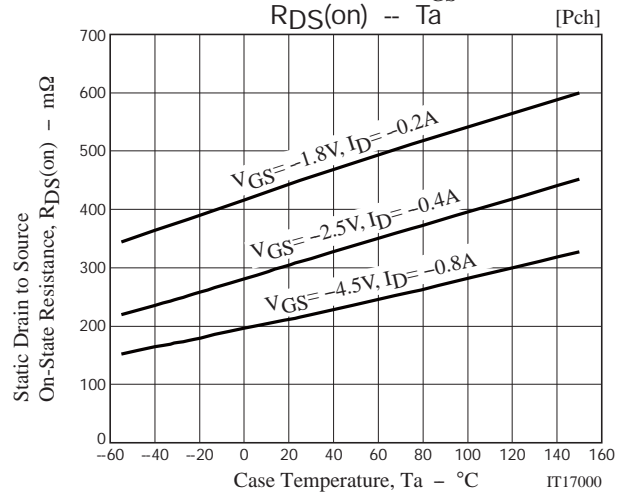
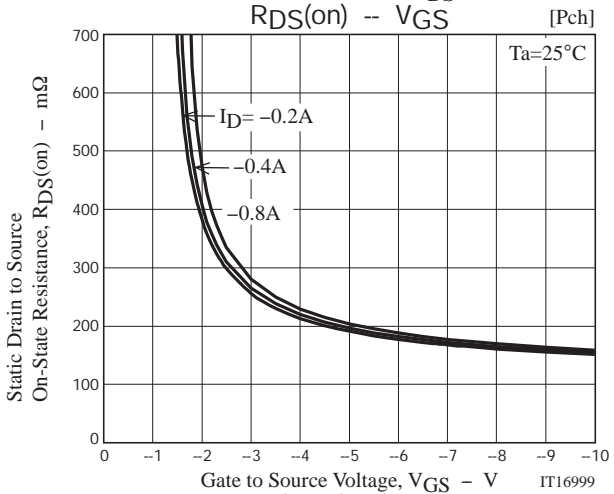
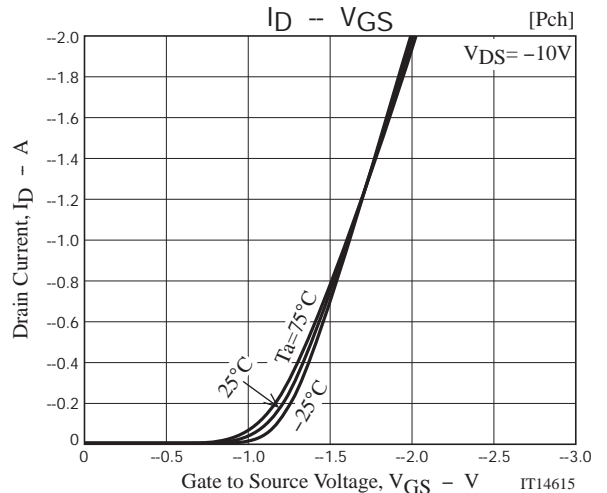
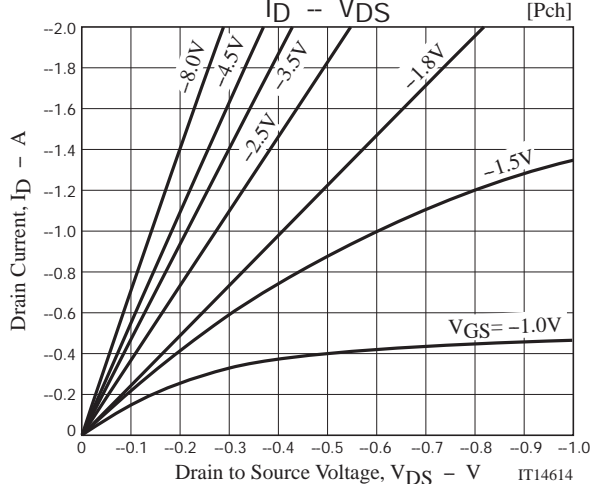
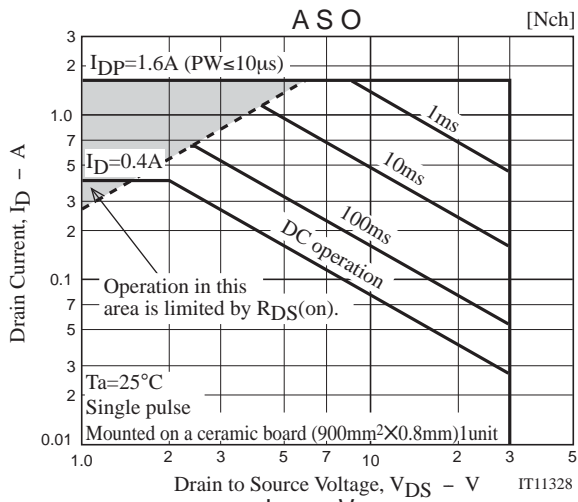
[N-channel]

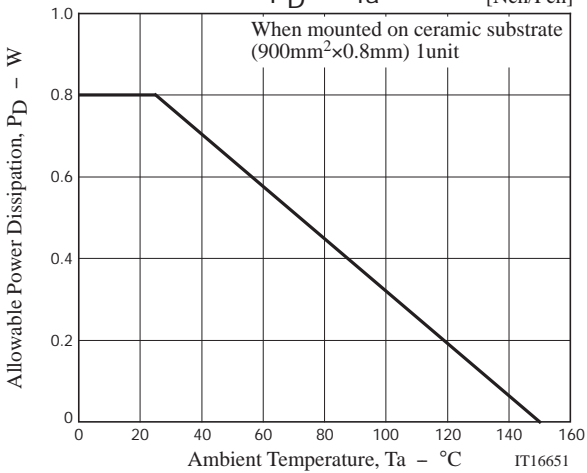
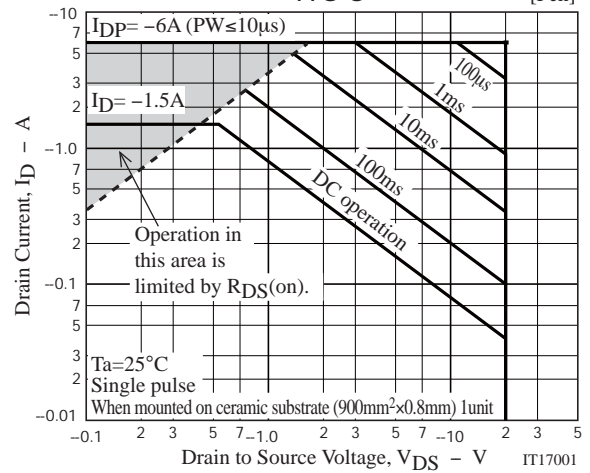
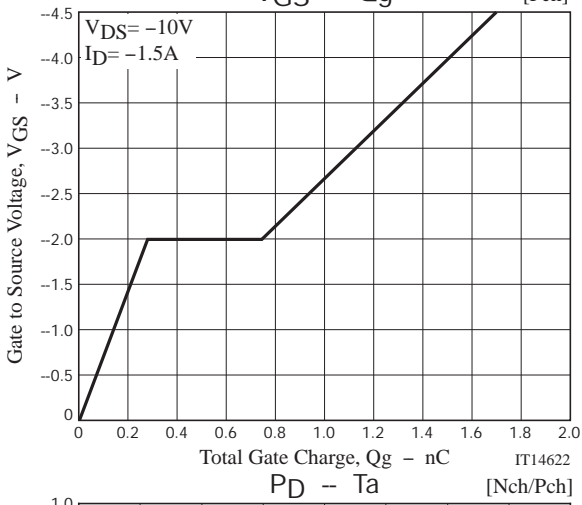
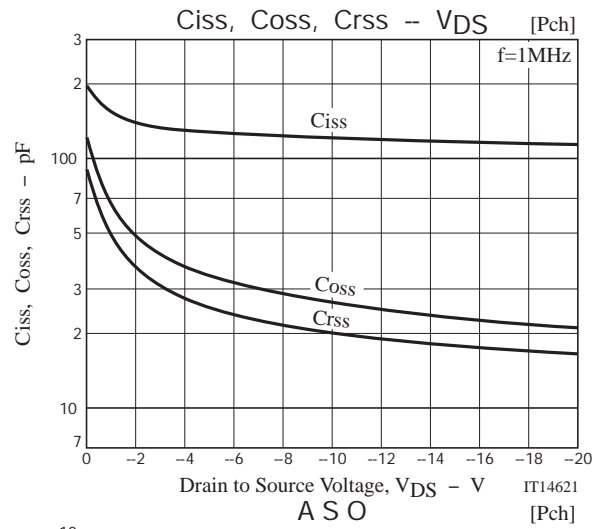
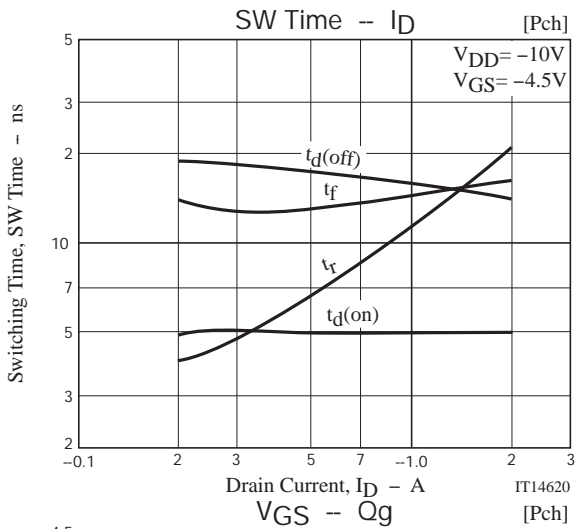


[P-channel]



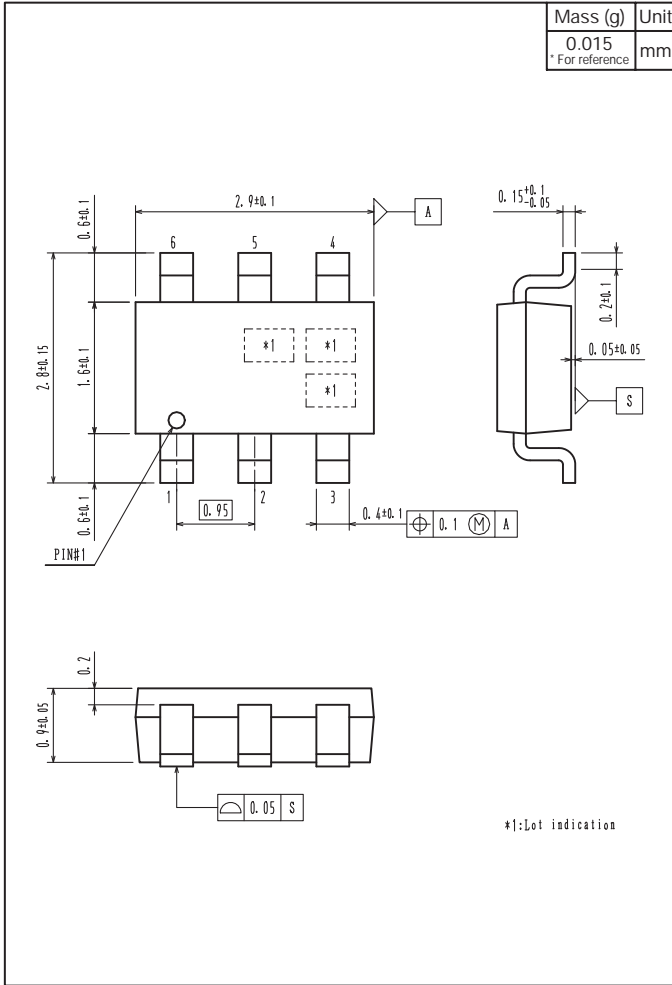




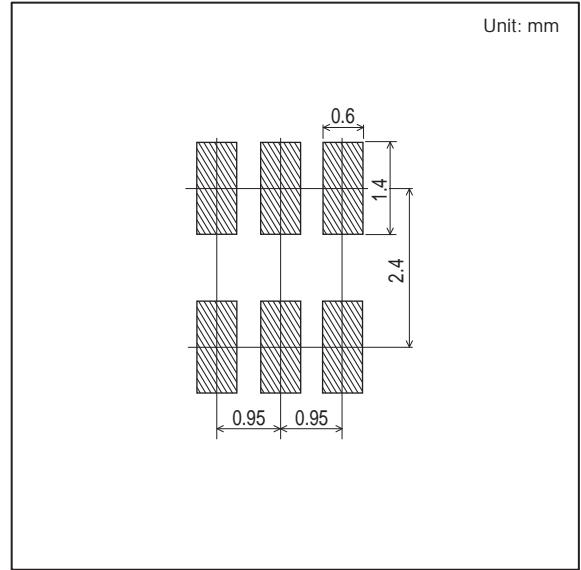


# CPH6635

## Outline Drawing CPH6635-TL-H



## Land Pattern Example



Note on usage : Since the CPH6635 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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